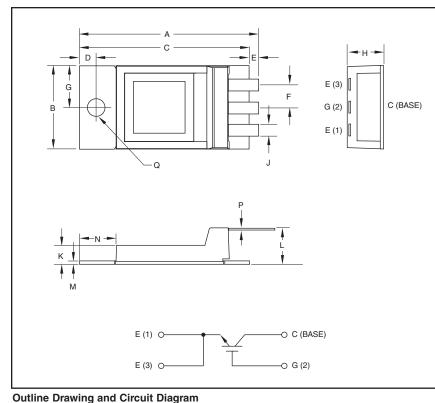


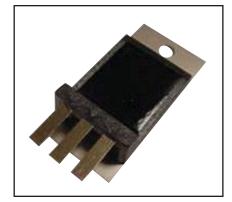
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Single Discrete IGBT 60 Amperes/4500 Volts



•				
Dimensions	Inches	Millimeters		
А	2.11	53.6		
В	0.98	25.0		
С	2.01	51.0		
D	0.2	5.0		
E.	0.1	2.5		
F	0.27	6.9		
G	0.49	12.5		
Н	0.46 Max.	11.8 Max.		

Dimensions	Inches	Millimeters
Dimensions	menes	winnineters
J	0.14	3.6
К	0.22	5.7
L	0.43	10.8
М	0.04	1.0
Ν	0.43	10.9
Р	0.02	0.5
Q	0.21 Dia.	5.3 Dia.



Description:

Powerex Single Non-isolated Discrete is designed specially for customer high voltage switching and pulse power applications.

Features:

- Low Drive Requirement
- □ Low V_{CE(sat)}
- Non-Isolated Molybdenum Mounting Plate
- □ IGBT is designed to be used by being immersed in oil or conformal coated in assembly



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QIS4506001

Single Discrete IGBT 60 Amperes/4500 Volts

Maximum Ratings, T_i = 25 °C unless otherwise specified

Ratings	Symbol	QIS4506001	Units
Collector Emitter Voltage	V _{CES}	4500	Volts
Gate Emitter Voltage	V _{GES}	±20	Volts
Collector Current (DC, $T_C = 127^{\circ}C$)	۱ _C	60	Amperes
Peak Collector Current (Pulsed)	I _{CM}	120*	Amperes
Junction Temperature	Тj	-55 to 150	°C
Storage Temperature	T _{stg}	-55 to 125	°C
Mounting Torque, M5 Mounting Screws	_	30	in-lb
Weight (Typical)	_	20	Grams

Static Electrical Characteristics, $T_i = 25$ °C unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Collector Cutoff Current	ICES	$V_{CE} = V_{CES}, V_{GE} = 0V$	_	_	1.0	mA
Gate Leakage Current	IGES	$V_{GE} = V_{GES}, V_{CE} = 0V$	_	_	0.5	μA
Gate-Emitter Threshold Voltage	V _{GE(th)}	$I_{C} = 7mA, V_{CE} = 10V$	4.5	6.0	7.5	Volts
Collector-Emitter Saturation Voltage	V _{CE(sat)}	$I_{C} = 60A, V_{GE} = 15V, T_{j} = 25^{\circ}C$	_	3.0	3.9**	Volts
		$I_{C} = 60A, V_{GE} = 15V, T_{j} = 125^{\circ}C$	_	3.6	_	Volts
Total Gate Charge	Q _G	V_{CC} = 2250V, I_{C} = 60A, V_{GE} = 15V	_	450	_	nC

Dynamic Electrical Characteristics, T_i = 25 °C unless otherwise specified

Characteristics		Symbol	Test Conditions	Min.	Typ.	Max.	Units
Input Capacitan	се	Cies		_	9.0	_	nF
Output Capacita	ance	C _{oes}	V _{GE} = 0V, V _{CE} = 10V		0.65	_	nF
Reverse Transfe	er Capacitance	C _{res}			0.2		nF
Resistive	Turn-on Delay Time	t _{d(on)}	$V_{CC} = 2250V,$			2.4	μs
Load	Rise Time	t _r	I _C = 60A,			2.4	μs
Switching	Turn-off Delay Time	t _{d(off)}	$V_{GE1} = V_{GE2} = 15V,$			6.0	μs
Times	Fall Time	t _f	R _G = 120Ω			1.2	μs
Turn-on Switchin	ng Energy	Eon	$T_j = 125^{\circ}C, I_C = 60A, V_{CC} = 2250V,$	_	250	—	mJ/P
Turn-off switchin	ng Energy	E _{off}		_	170	_	mJ/P

Thermal and Mechanical Characteristics, $T_i = 25$ °C unless otherwise specified

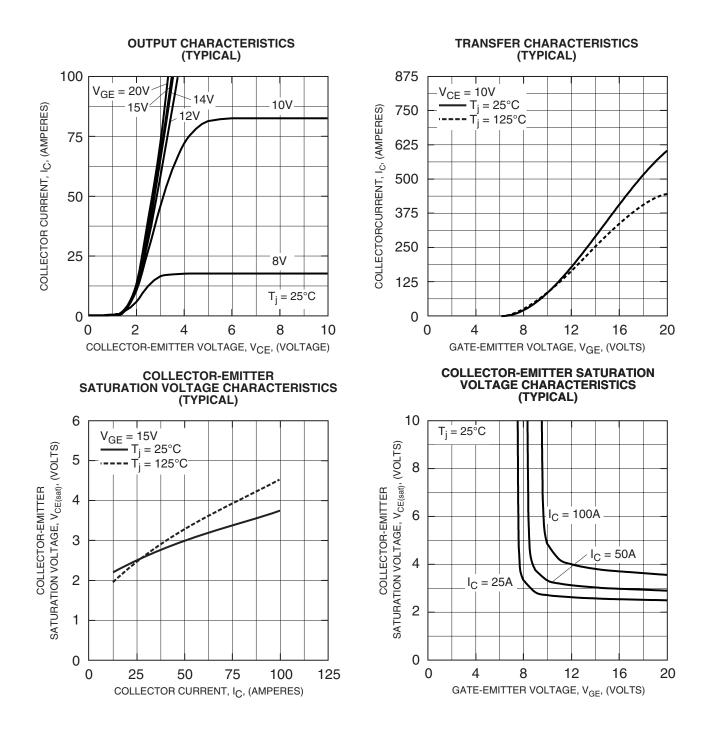
Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance, Junction to Case	R _{th(j-c)}	IGBT	—	0.10	0.12	°C/W
Thermal Resistance, Case to Sink	R _{th(c-s)}	$\lambda_{grease} = 1W/mK$	_	0.10	_	°C/W
Thermal Grease Applied						

* Pulse width and repetition rate should be such that device junction temperature (Tj) does not exceed device rating.
**Pulse width and repetition rate should be such that device junction temperature rise is negligible.



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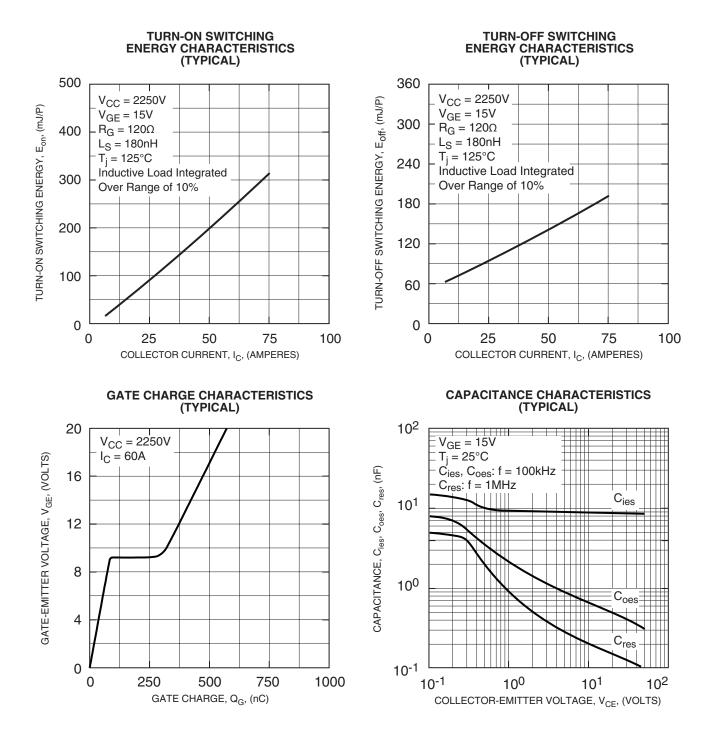




Preliminary

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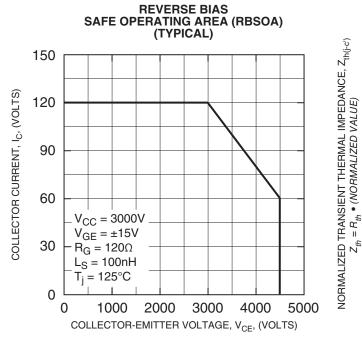


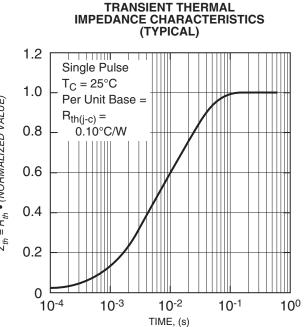


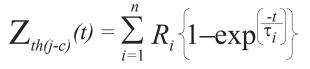
Preliminary

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QIS4506001 Single Discrete IGBT 60 Amperes/4500 Volts







	1	2	3	4
R_i (°C/W)	-6.55E-03	1.66E-02	6.24E-03	8.32E-02
τ_i (sec)	3.33E-04	7.57-E-04	2.34E-03	1.34E-02